



IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant : S. Kikuchi et al.

Art Unit : 2822

Serial No. : 09/837,397

Examiner : Lewis, Monica

Filed : April 18, 2001

Title : SEMICONDUCTOR DEVICE AND METHOD OF MANUFACTURING THE SAME

Commissioner for Patents
Washington, D.C. 20231

RESPONSE

In response to the action mailed September 13, 2002, please amend the application as follows:

In the specification:

Please replace the title at page 1, line 1 with the following:

-- SEMICONDUCTOR DEVICE FOR IMPROVING SUSTAINING
VOLTAGE--

In the claims:

Please amend claims 1 to 6 as follows:

- 1. (Amended) A semiconductor device comprising:
- a semiconductor substrate of a first conductive type;
 - a gate insulation film disposed over the semiconductor substrate;
 - a gate electrode provided on the gate insulation film;

CERTIFICATE OF MAILING BY FIRST CLASS MAIL

I hereby certify under 37 CFR §1.8(a) that this correspondence is being deposited with the United States Postal Service as first class mail with sufficient postage on the date indicated below and is addressed to the Commissioner for Patents, Washington, D.C. 20231.

Date of Deposit

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January 8, 2003
Carol Tyrrell
Carol Tyrrell